

SAMTM Data Sheet SAM-1064-22-47ps-x, λ = 1064 nm

Laser wavelength $\lambda = 1064 \text{ nm}$

High reflection band $\lambda = 1020 ... 1100 \text{ nm}$

Reflectance at 808 nm $R_{808} = 50 \%$ Absorbance $A_0 = 22 \%$ Modulation depth $\Delta R = 13 \%$ Non-saturable loss $A_{ns} = 9 \%$

Saturation fluence $\Phi_{sat} = 49 \,\mu\text{J/cm}^2$

Relaxation time constant $\tau \sim 47 \text{ ps}$

Damage threshold $\Phi = 2 \text{ mJ/cm}^2$

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

Dielectric coating HR @ 808 nm and AR @ 1064 nm

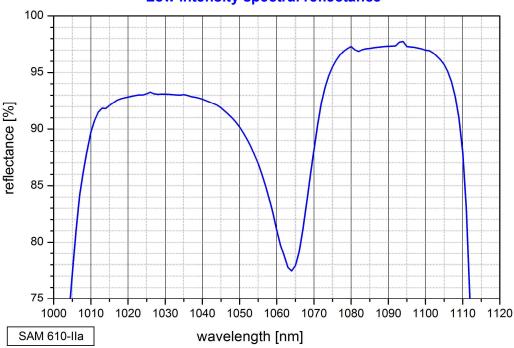
Mounting option **x** denotes the type of mounting as follows:

x = 0 unmounted

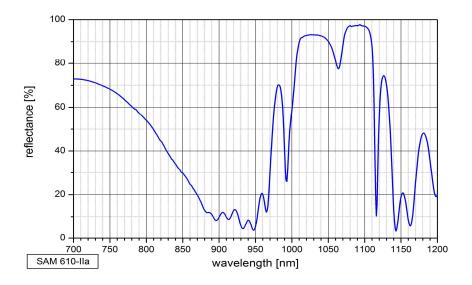
 $x = 12.7 \, \mathrm{g}$ glued on a copper heat sink with 12.7 mm \varnothing $x = 25.4 \, \mathrm{g}$ glued on a copper heat sink with 25.4 mm \varnothing $x = 12.7 \, \mathrm{s}$ soldered on a copper heat sink with 12.7 mm \varnothing $x = 25.4 \, \mathrm{s}$ soldered on a copper heat sink with 25.4 mm \varnothing

x = 25.4 w soldered on a water cooled copper heat sink with 25.4 mm Ø mounted on a 1 m monomode fiber cable with FC connector

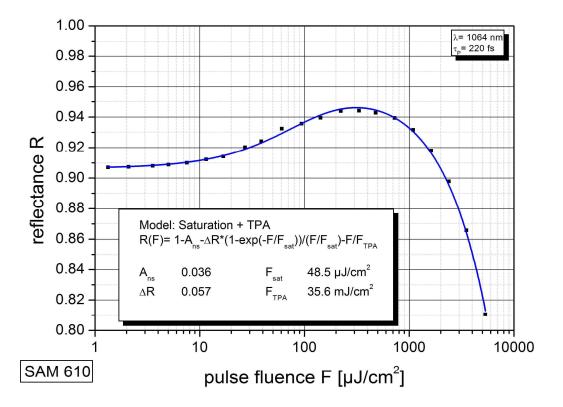
Low intensity spectral reflectance







Saturation measurement





Pump-probe measurement

